NSN 5962-01-179-3618

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-179-3618 **Body Length:** 1.290 inches **Body Width:** Between 0.500 inches and 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.8 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+125.0 degrees celsius **End Application:** 1260011110148 **Features Provided:** Hermetically sealed and burn in and erasable and programmable and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 21 input **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 6.0 volts power source **Time Rating Per Chacteristic:** 300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Test Data Document:** 07187-8001760 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 24 printed circuit Shelf Life:

Demilitarization: Yes - demil/mli

Unit Of Measure:

N/a

NSN 5962-01-179-3618

Memory Microcircuit - Page 2 of 2



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